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SUD40151EL

Vishay Siliconix

RoHS

COMPLIANT

HALOGEN

P-Channel 40 V (D-S) 175 °C MOSFET



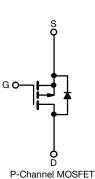
| PRODUCT SUMMARY | | |
|--|--------|--|
| V _{DS} (V) | -40 | |
| $R_{DS(on)}$ max. (Ω) at V_{GS} = 10 V | 0.0120 | |
| $R_{DS(on)}$ max. (Ω) at V_{GS} = 4.5 V | 0.0175 | |
| Q _g typ. (nC) | 74.3 | |
| I _D (A) ^d | -42 | |
| Configuration | Single | |

FEATURES

- TrenchFET[®] Gen IV p-channel power MOSFET
- Maximum 175 °C junction temperature
- 100 % R_g and UIS tested
- Material categorization: for definitions of FREE compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Motor drive control
- LED backlighting
- Load switch
- Industrial



| ORDERING INFORMATION | | |
|---------------------------------|----------------|--|
| Package | TO-252 | |
| Lead (Pb)-free and halogen-free | SUD40151EL-GE3 | |

| ABSOLUTE MAXIMUM RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted) | | | | |
|---|-------------------------|-----------------------------------|-------------------|------|
| PARAMETER | | SYMBOL | LIMIT | UNIT |
| Drain-source voltage | | V _{DS} | -40 | V |
| Gate-source voltage | | V _{GS} | ± 20 | v |
| Continuous drain current | T _C = 25 °C | | -42 ^d | |
| | T _C = 125 °C | - I _D | -28.6 | |
| Pulsed drain current (t = 100 μs) | | I _{DM} | -100 | A |
| Continuous source-drain diode current | | IS | -41.7 | |
| Single pulse avalanche current ^a | L = 0.1 mH | I _{AS} | -25 | |
| Single pulse avalanche energy ^a | L = 0.1 MH | E _{AS} | 31.25 | mJ |
| Maximum power dissipation | T _C = 25 °C | _ | 50 ^b | |
| | T _C = 125 °C | P _D | 16.7 ^b | W |
| Operating junction and storage temperature range | | T _J , T _{stg} | -55 to +175 | *0 |
| Soldering recommendations (peak temperature) ^c | | | 260 | |

| THERMAL RESISTANCE RATINGS | | | | |
|--|--------------|-------------------|---------|------|
| PARAMETER | | SYMBOL | MAXIMUM | UNIT |
| Maximum junction-to-ambient (PCB mount) ^c | | R _{thJA} | 60 | °C/W |
| Maximum junction-to-case (drain) | Steady state | R _{thJC} | 3 | 0/10 |

Notes

a. Duty cycle \leq 1 %

b. See SOA curve for voltage derating

c. When mounted on 1" square PCB (FR4 material)

d. Package limited

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| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNIT | |
|---|----------------------|--|------|--------|--------|------|--|
| Static | • | | • | | • | | |
| Drain-source breakdown voltage | V _{DS} | $V_{GS} = 0 \text{ V}, \text{ I}_{D} = -250 \mu\text{A}$ | -40 | - | - | V | |
| Gate-source threshold voltage | V _{GS(th)} | $V_{DS} = V_{GS}, I_D = -250 \ \mu A$ | -1.5 | - | -2.5 | V | |
| Gate-source leakage | I _{GSS} | $V_{DS} = 0 V, V_{GS} = \pm 20 V$ | - | - | 250 | nA | |
| | | $V_{DS} = -40 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$ | - | - | -1 | μΑ | |
| Zero gate voltage drain current | I _{DSS} | V_{DS} = -40 V, V_{GS} = 0 V, T_{J} = 125 °C | - | - | -150 | | |
| | | V_{DS} = -40 V, V_{GS} = 0 V, T_{J} = 175 °C | - | - | -5 | mA | |
| On-state drain current ^a | I _{D(on)} | $V_{DS} \geq$ -10 V, V_{GS} = -10 V | -30 | - | - | Α | |
| Drain-source on-state resistance ^a | Р | V _{GS} = -10 V, I _D = -17.5 A | - | 0.0100 | 0.0120 | | |
| Drain-source on-state resistance " | R _{DS(on)} | $V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -14.5 \text{ A}$ | - | 0.0135 | 0.0175 | Ω | |
| Forward transconductance ^a | 9 _{fs} | V _{DS} = -10 V, I _D = -17.5 A | - | 70 | - | S | |
| Dynamic ^b | | | | | | | |
| Input capacitance | Ciss | | - | 5340 | - | pF | |
| Output capacitance | C _{oss} | V_{DS} = -20 V, V_{GS} = 0 V, f = 1 MHz | - | 335 | - | | |
| Reverse transfer capacitance | C _{rss} | | - | 303 | - | | |
| Total gate charge | Qg | | - | 74.3 | 112 | nC | |
| Gate-source charge | Q _{gs} | V_{DS} = -20 V, V_{GS} = -10 V, I_D = -17.5 A | - | 12.7 | - | | |
| Gate-drain charge | Q _{gd} | | - | 11.1 | - | | |
| Gate resistance | Rg | f = 1 MHz | 0.86 | 4.3 | 8.6 | Ω | |
| Turn-on delay time | t _{d(on)} | | - | 15 | 30 | | |
| Rise time | t _r | $V_{DD} = -20 \text{ V}, \text{ R}_{L} = 1.4 \Omega, \text{ I}_{D} \cong -14 \text{ A},$ | - | 10 | 20 | | |
| Turn-off delay time | t _{d(off)} | V_{GEN} = -10 V, R_g = 1 Ω | - | 75 | 113 | - ns | |
| Fall time | t _f | | - | 75 | 113 | | |
| Drain-Source Body Diode Characteristi | cs | | • | | • | | |
| Pulse diode forward current (t = 100 µs) | I _{SM} | | - | - | -42 | Α | |
| Body diode voltage | V _{SD} | I _F = -14 A, V _{GS} = 0 V | - | -0.85 | -1.5 | V | |
| Body diode reverse recovery time | t _{rr} | | - | 30 | 45 | ns | |
| Body diode reverse recovery charge | Q _{rr} | | - | 0.02 | 0.04 | μC | |
| Reverse recovery fall time | t _a | I _F = -14 A, di/dt = 100 A/μs | - | 15.3 | - | | |
| Reverse recovery rise time | t _b | | - | 14.7 | - | ns | |
| Body diode peak reverse recovery charge | I _{RM(REC)} | | - | - | 2.8 | Α | |

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing

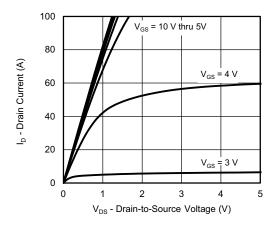
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c. Independent of operating temperature

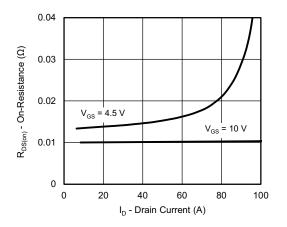
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



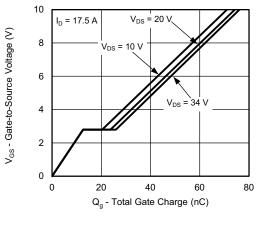
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



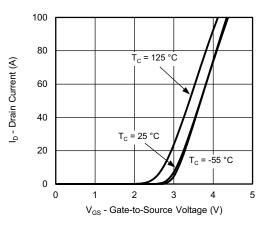
Output Characteristics



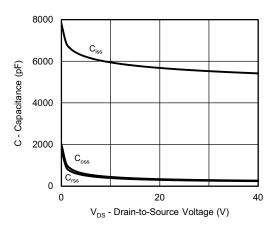
On-Resistance vs. Drain Current and Gate Voltage



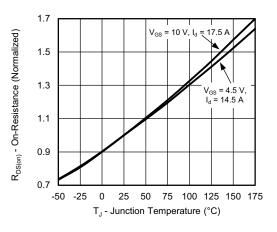
Gate Charge



Transfer Characteristics



Capacitance



On-Resistance vs. Junction Temperature

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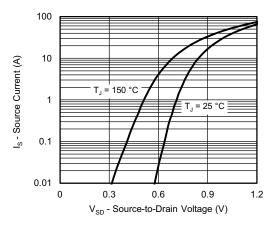
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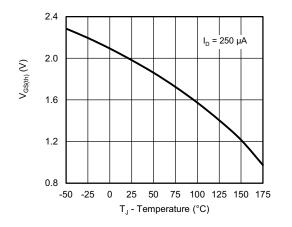
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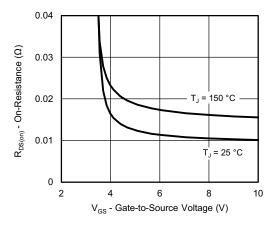
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



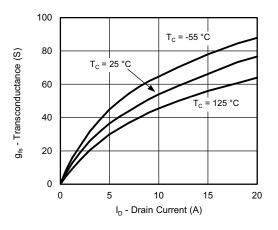
Source-Drain Diode Forward Voltage



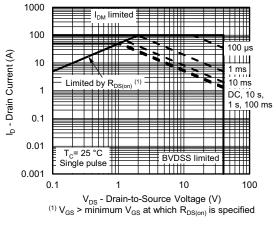
Threshold Voltage



On-Resistance vs. Gate-to-Source Voltage





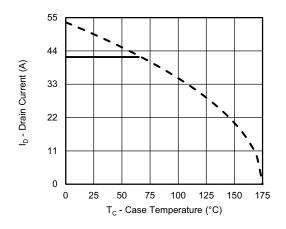


Safe Operating Area, Junction-to-Ambient

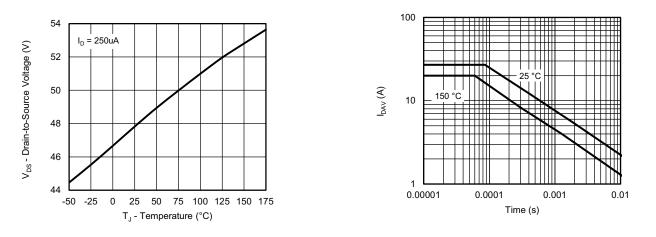
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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)







Drain Source Breakdown vs. Junction Temperature

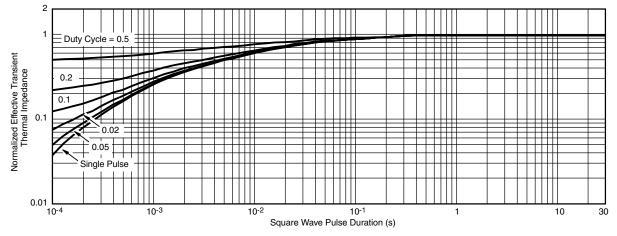
I_{DAV} vs. Time

Note

a. The power dissipation P_D is based on T_J max. = 25 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

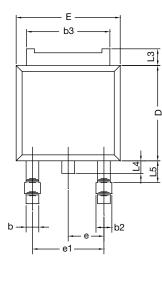
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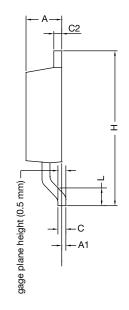




TO-252AA Case Outline

VERSION 1: FACILITY CODE = Y







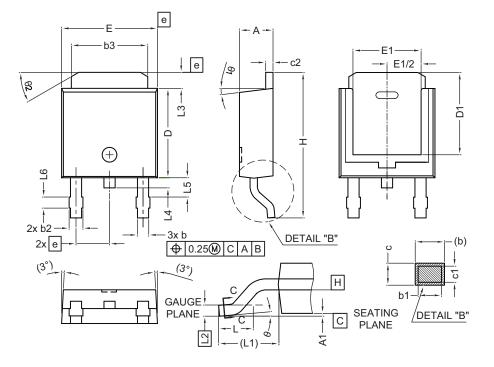
| | MILLIMETERS | | |
|------|-------------|-------|--|
| DIM. | MIN. | MAX. | |
| А | 2.18 | 2.38 | |
| A1 | - | 0.127 | |
| b | 0.64 | 0.88 | |
| b2 | 0.76 | 1.14 | |
| b3 | 4.95 | 5.46 | |
| С | 0.46 | 0.61 | |
| C2 | 0.46 | 0.89 | |
| D | 5.97 | 6.22 | |
| D1 | 4.10 | - | |
| E | 6.35 | 6.73 | |
| E1 | 4.32 | - | |
| Н | 9.40 | 10.41 | |
| е | 2.28 BSC | | |
| e1 | 4.56 BSC | | |
| L | 1.40 | 1.78 | |
| L3 | 0.89 | 1.27 | |
| L4 | - 1.02 | | |
| L5 | 1.01 | 1.52 | |

Note

• Dimension L3 is for reference only



VERSION 2: FACILITY CODE = N



| | MILLIMETERS | | |
|------|-------------|------|--|
| DIM. | MIN. | MAX. | |
| А | 2.18 | 2.39 | |
| A1 | - | 0.13 | |
| b | 0.65 | 0.89 | |
| b1 | 0.64 | 0.79 | |
| b2 | 0.76 | 1.13 | |
| b3 | 4.95 | 5.46 | |
| с | 0.46 | 0.61 | |
| c1 | 0.41 | 0.56 | |
| c2 | 0.46 | 0.60 | |
| D | 5.97 | 6.22 | |
| D1 | 5.21 | - | |
| E | 6.35 | 6.73 | |
| E1 | 4.32 - | | |
| e | 2.29 BSC | | |
| Н | 9.94 10.34 | | |

| | MILLIMETERS | | |
|------|-------------|------|--|
| DIM. | MIN. | MAX. | |
| L | 1.50 | 1.78 | |
| L1 | 2.74 ref. | | |
| L2 | 0.51 BSC | | |
| L3 | 0.89 | 1.27 | |
| L4 | - | 1.02 | |
| L5 | 1.14 | 1.49 | |
| L6 | 0.65 | 0.85 | |
| θ | 0° | 10° | |
| θ1 | 0° | 15° | |
| θ2 | 25° 35° | | |

Notes

Dimensioning and tolerance confirm to ASME Y14.5M-1994

All dimensions are in millimeters. Angles are in degrees

Heat sink side flash is max. 0.8 mm

Radius on terminal is optional ٠

ECN: E19-0649-Rev. Q, 16-Dec-2019 DWG: 5347



RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

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